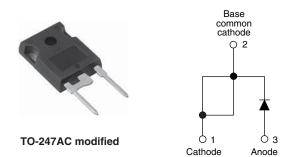
Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt[®]



PRODUCT SUMMARY									
Package	TO-247AC modified (2 pins)								
I _{F(AV)}	30 A								
V _R	600 V								
V _F at I _F	2.6 V								
t _{rr} typ.	See Recovery table								
T _J max.	175 °C								
Diode variation	Single die								

FEATURES

- · Hyperfast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Single diode device
- Compliant to RoHS Directive 2002/95/EC
- Designed and gualified for industrial level

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 116 °C	30	٨						
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	300	A						
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C						

ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-				
Commend wells as	VF	I _F = 30 A	-	2.0	2.6	V			
Forward voltage	۷F	I _F = 30 A, T _J = 150 °C	-	1.34	1.75				
Povoroo lookogo ourront	1	V _R = V _R rated	-	0.3	50				
Reverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	60	500	μA			
Junction capacitance	ion capacitance C_T $V_R = 600 V$		-	33	-	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	3.5	-	nH			



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VS-30EPH06PbF

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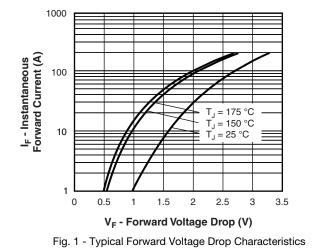
DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS				
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	-	28	35					
Reverse recovery time	t _{rr}	T _J = 25 °C		-	31	-	ns A			
		T _J = 125 °C	I _F = 30 A dI _F /dt = 200 A/μs V _R = 200 V	-	77	-				
Dock receivery ourrest	I _{RRM}	$T_J = 25 \ ^\circ C$		-	3.5	-				
Peak recovery current		T _J = 125 °C		-	7.7	-				
Reverse recovery charge	Q _{rr}	$T_J = 25 \ ^\circ C$		-	65	-	nC			
		T _J = 125 °C		-	345	-	nc			

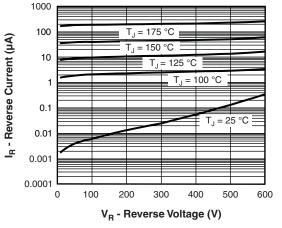
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER SYMBO		TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C			
Thermal resistance, junction to case per leg	R _{thJC}		-	0.5	0.9				
Thermal resistance, junction to ambient per leg		Typical socket mount	-	-	70	°C/W			
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.4	-	-			
Weight			-	6.0	-	g			
Weight			-	0.22	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style TO-247AC modified	30EPH06						

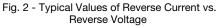


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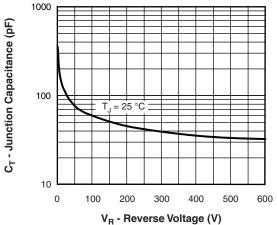


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

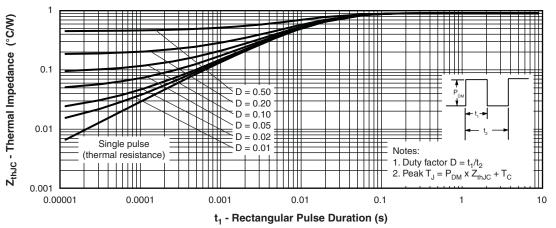


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com,

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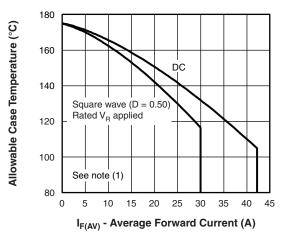
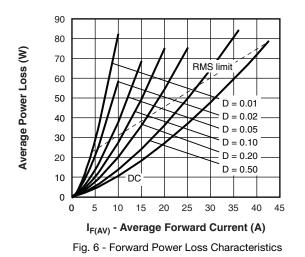


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ \mathsf{-D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

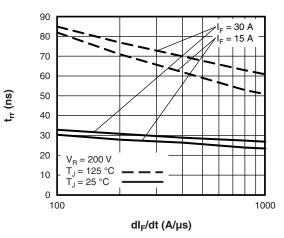
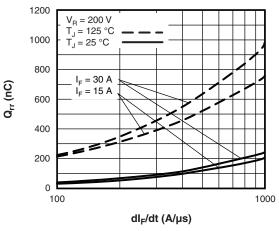


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt





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Hyperfast Rectifier, 30 A FRED Pt[®] V

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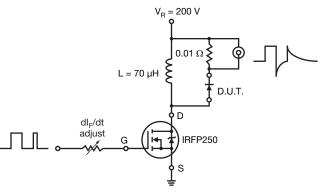
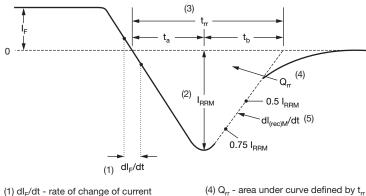
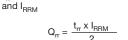


Fig. 9 - Reverse Recovery Parameter Test Circuit



(1) dI_F/dt - rate of change of current through zero crossing



(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(2) I_{RRM} - peak reverse recovery current

(5) dI_{(rec)M}/dt - peak rate of change of current during $t_{\rm b}$ portion of $t_{\rm rr}$

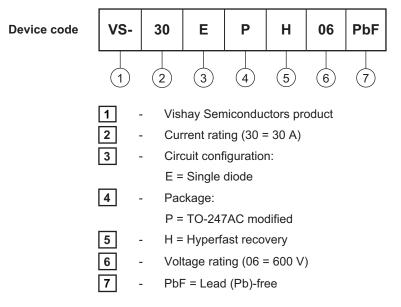
Fig. 10 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE



Tube standard pack quantity: 25 pieces

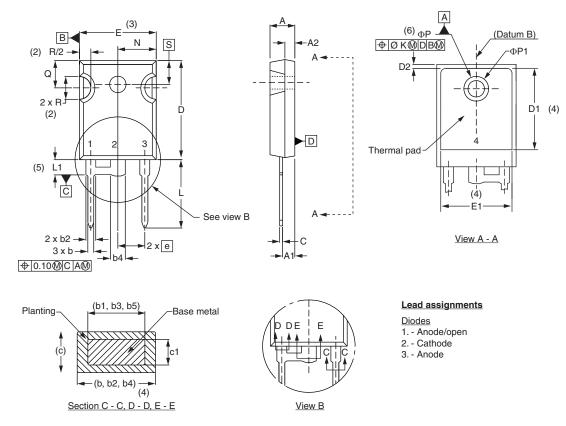
LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95253							
Part marking information	www.vishay.com/doc?95255						

Outline Dimensions





DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ΦK	2.	54	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.37	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ΦР	3.56	3.66	0.14	0.144	
С	0.38	0.86	0.015	0.034			Φ P1	-	6.98	-	0.275	
c1	0.38	0.76	0.015	0.030			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	1.78	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

Notes

⁽¹⁾ Dimensioning and tolerance per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1

(6) ΦP to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC outline TO-247 with exception of dimension c

Revision: 21-Jun-11

1

Document Number: 95253

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